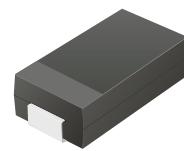


CEFB201-G Thru. CEFB205-G

Reverse Voltage: 50 to 600 Volts

Forward Current: 2.0 Amp

RoHS Device

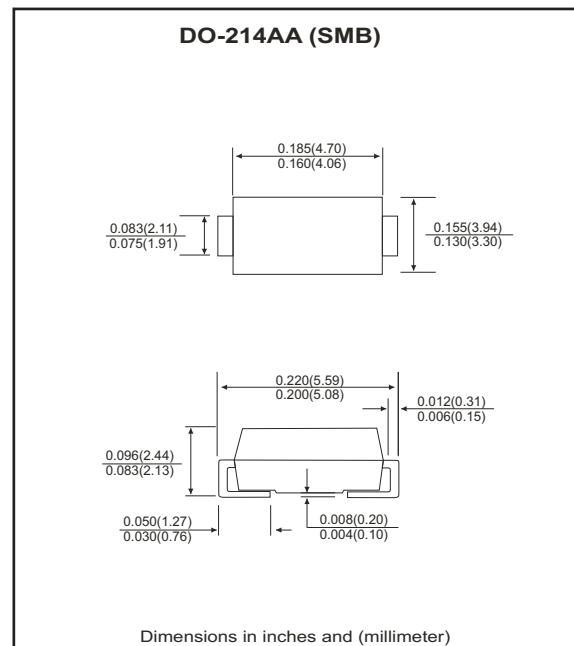


Features

- Ideal for surface mount applications.
- Easy pick and place.
- Plastic package has Underwriters Lab. flammability classification 94V-0.
- Super fast recovery time for high efficient.
- Built-in strain relief.
- Low forward voltage drop.

Mechanical data

- Case: JEDEC DO-214AA, molded plastic.
- Terminals: solderable per MIL-STD-750, method 2026.
- Polarity: Color band denotes cathode end.
- Approx. weight: 0.093 grams



Maximum Ratings and Electrical Characteristics

Parameter	Symbol	CEFB201-G	CEFB202-G	CEFB203-G	CEFB204-G	CEFB205-G	Units
Max. repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	V
Max. DC blocking voltage	V _{DC}	50	100	200	400	600	V
Max. RMS voltage	V _{RMS}	35	70	140	280	420	V
Peak surge forward current, 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}		35		45		A
Max. average forward current	I _o		2.0				A
Max. instantaneous forward voltage at 2.0A	V _F		0.875		1.1	1.25	V
Reverse recovery time	T _{rr}		25		35	50	nS
Max. DC reverse current at T _A =25 °C rated DC blocking voltage T _A =100 °C	I _R			5.0 250			µA
Max. thermal resistance (Note 1)	R _{θJL}		15				°C/W
Max. operating junction temperature	T _J		150				°C
Storage temperature	T _{STG}		-55 to +150				°C

Notes: 1. Thermal resistance from junction to lead mounted on P.C.B. with 8.0×8.0 mm copper² pad area.

SMD Efficient Fast Recovery Rectifiers

Comchip
SMD Diode Specialist

RATING AND CHARACTERISTIC CURVES (CEFB201-G thru CEFB205-G)

Fig.1 Reverse Characteristics

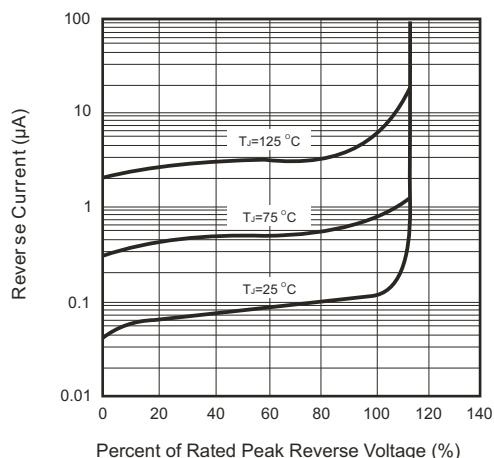


Fig.2 Forward Characteristics

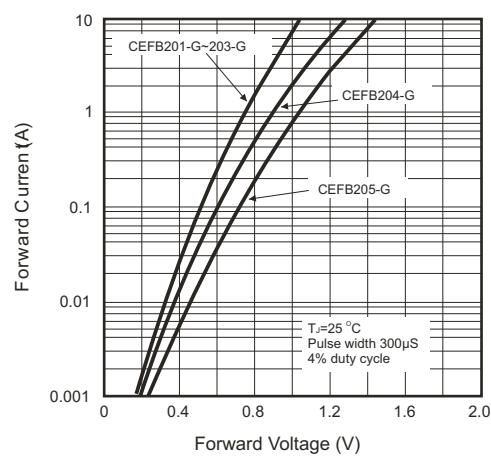


Fig.3 Junction Capacitance

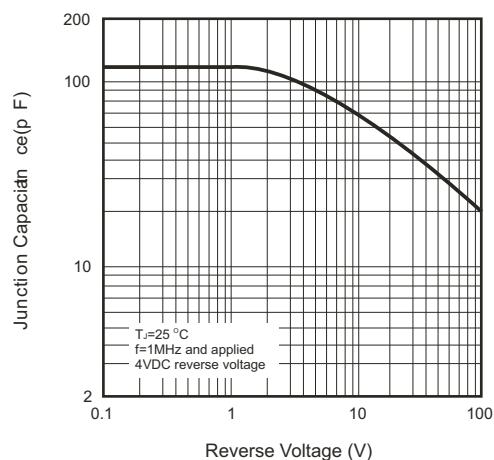


Fig.4 Non-repetitive Forward Surge Current

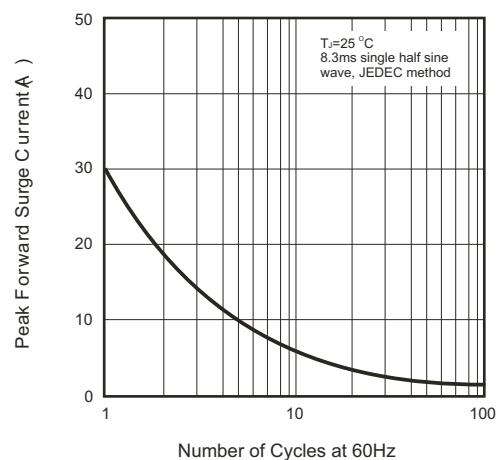


Fig.5 Test Circuit Diagram and Reverse Recovery Time Characteristics

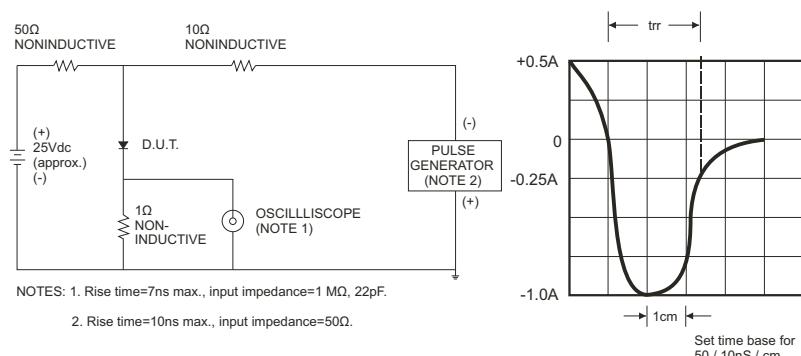


Fig.6 Current Derating Curve

